MGBR20L300 DIODE

MOS GATED BARRIER RECTIFIER

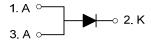
DESCRIPTION

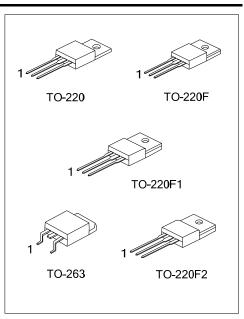
The UTC **MGBR20L300** is a surface mount mos gatedbarrier rectifier,it uses UTC's advanced technology to provide customers withlow forward voltage drop and high switching speed, etc.

■ FEATURES

- * Low forward voltage drop
- * High switching speed

■ SYMBOL

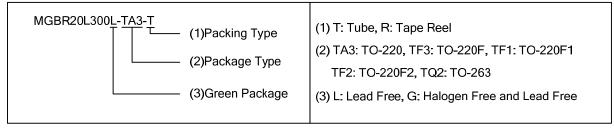




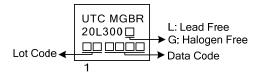
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR20L300L-TA3-T	MGBR20L300G-TA3-T	TO-220	Α	K	Α	Tube	
MGBR20L300L-TF3-T	MGBR20L300G-TF3-T	TO-220F	Α	K	Α	Tube	
MGBR20L300L-TF1-T	MGBR20L300G-TF1-T	TO-220F1	Α	K	Α	Tube	
MGBR20L300L-TF2-T	MGBR20L300G-TF2-T	TO-220F2	Α	K	Α	Tube	
MGBR20L300L-TQ2-T	MGBR20L300G-TQ2-T	TO-263	Α	K	Α	Tube	
MGBR20L300L-TQ2-R	MGBR20L300G-TQ2-R	TO-263	Α	K	Α	Tape Reel	

Note: Pin Assignment: A: Anode K: Common Cathode



■ MARKING



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V_{RM}	300	V
Working Peak Reverse Voltage		V_{RWM}	300	V
Peak Repetitive Reverse Voltage		V_{RRM}	300	V
Average Rectified Output Current	T _C =140°C	Io	20	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	235	Α
Operating Junction Temperature		TJ	-65~+150	°C
Storage Temperature		T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (Note 3)

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient		θ_{JA}	62.5	°C/W	
Junction to Case	TO-220/TO-263		2		
	TO-220F/TO-220F1 TO-220F2	θЈС	4	°C/W	

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C,unless otherwise specified.)

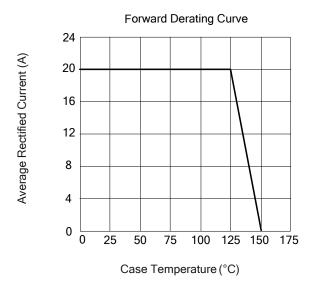
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.5mA	300			V
Forward Voltage Drop	VEM	I _F =20A, T _J =25°C		0.88	0.92	V
		I _F =20A, T _J =125°C		0.80	0.81	V
Leakage Current (Note 1)	Iрм	V _R =300V, T _J =25°C			100	μΑ
		V _R =300V, T _J =125°C			10	mA

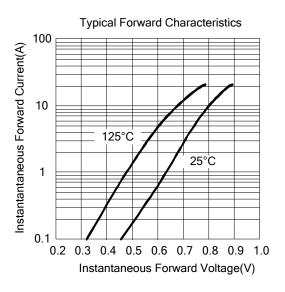
Notes: 1. Short duration pulse test used to minimize self-heating effect.

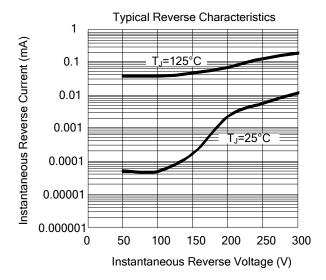
- 2. Thermal resistance junction to case mounted on heatsink.
- 3. Mounted on an FR4 PCB, single-sided copper, with 100 cm² copper pad area.

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■ TYPICAL CHARACTERISTICS







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